



HN1B04FE-GR,LF Information



For Reference Only

Part Number HN1B04FE-GR,LF

ManufacturerToshiba Semiconductor and StorageCategoryDiscrete Semiconductor ProductsTransistors - Bipolar (BJT) - Arrays

Description TRANS NPN/PNP 50V 0.15A ES6

Package SOT-563, SOT-666

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









HN1B04FE-GR,LF Specifications

Manufacturer Part Number	HN1B04FE-GR,LF
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	SOT-563, SOT-666
Series	-
Transistor Type	NPN, PNP
Current - Collector (Ic) (Max)	150mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	250mV @ 10mA, 100mA
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	200 @ 2mA, 6V
Power - Max	100mW
Frequency - Transition	80MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-563, SOT-666
Supplier Device Package	ES6
	Report errors?

HN1B04FE-GR,LF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

HN1B04FE-GR,LF Payment Methods



















HN1B04FE-GR,LF Shipping Methods













If you have any question about HN1B04FE-GR, LF, please do not hesitate to contact us!

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